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**CONFIRMATION NO. 9450** 

SERIAL NUMBER 10/609,410	FILING DATE 07/01/2003 RULE	CLASS 438	GROUP ART 1 2891	HINIT I	ATTORNEY DOCKET NO. 160-386	
APPLICANTS						
Shuji Nakamura, Anan-shi, JAPAN;						
Takao Yamada, Anan-shi, JAPAN; Masayuki Senoh, Anan-shi, JAPAN;Motokazu Yamada, Anan-shi, JAPAN; Kanji Bando, Anan-shi, JAPAN;						
CONTINUING DATA						
This application is a DIV of 10/292,583 11/13/2002 PAT 6,610,995 which is a DIV of 09/750,912 01/02/2001 PAT 6,507,041 which is a DIV of 09/448,479 11/24/1999 PAT 6,204,512 which is a DIV of 09/209,826 12/11/1998 PAT 6,093,965 which is a DIV of 08/995,167 12/19/1997 PAT 5,877,558 which is a DIV of 08/670,242 06/17/1996 PAT 5,767,581 which is a DIV of 08/234,001 04/28/1994 PAT 5,563,422 * (*) Data provided by applicant is not consistent with PTO records.  **FOREIGN APPLICATIONS *** JAPAN 5-124890 04/28/1993 JAPAN 5-129313 05/31/1993 JAPAN 5-207274 07/28/1993						
JAPAN 5-23468: JAPAN 5-23468: JAPAN 5-25317 JAPAN 6-8726 0 JAPAN 6-8727 0	4 09/21/1993 5 09/21/1993 1 10/08/1993 01/28/1994	GRANTED				
Foreign Priority claimed	yes one	STATE OR	SHEETS	TOTAL	NOEDENIDENT	
35 USC 119 (a-d) conditions met Verified and Acknowledged Exam	Allowing no Met after Allowing Nov	COUNTRY	DRAWING 10	CLAIMS	INDEPENDENT CLAIMS 1	
ADDRESS 23117						

NIXON & VAND 1100 N GLEBE 8TH FLOOR ARLINGTON , V 22201-4714	ROAD	·			
TITLE Gallium nitride based III-V group compound semiconductor device and method of producing the same					
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		1.16 Fees (Filing)			
		1.17 Fees ( Pracessing Ext. of time )			
		1.18 Fees (Issue)			
		Other			
		☐ Credit			